

## Supporting Information

### Nonvolatile Transistor Memory Devices Based on High-k Electrets of Polyimide/TiO<sub>2</sub> Hybrids

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**Table S1.** Inherent Viscosity and Molecular Weights of the Polyimides

Polymer	$\eta_{inh}^a$ (dL/g)	$M_w^b$	$M_n^b$	PDI <sup>c</sup>
<b>PI(F-ODPA)</b>	0.72	115900	60300	1.92
<b>PI(3S-ODPA)</b>	0.45	98300	48200	2.03

<sup>a</sup> Measured at a polymer concentration of 0.5 g/dL in DMAc at 30 °C.

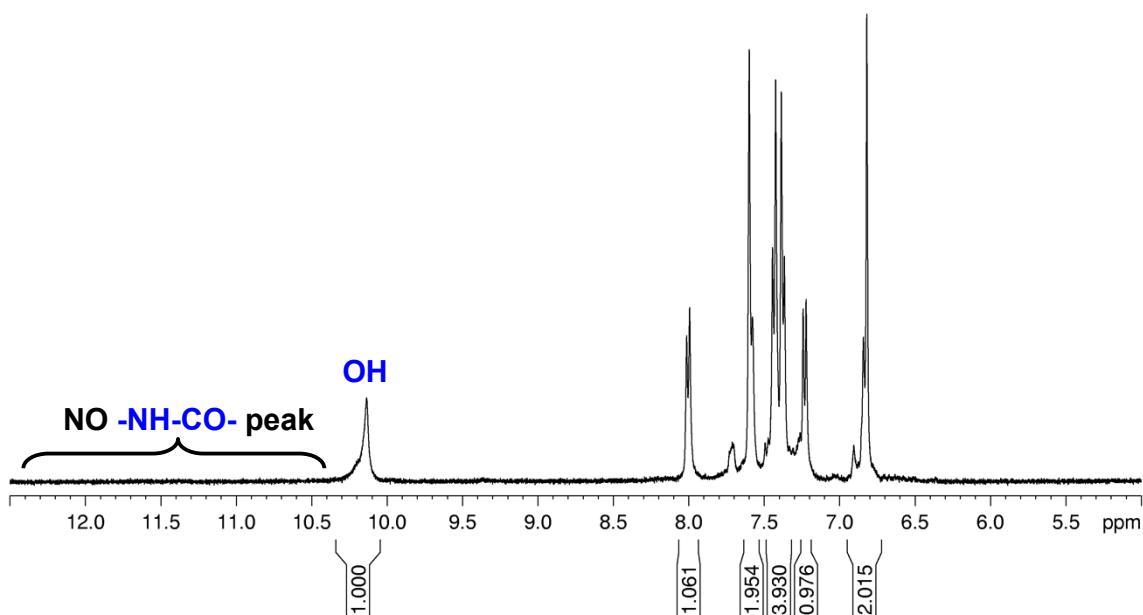
<sup>b</sup> Calibrated with polystyrene standards, using NMP as the eluent at a constant flow rate of 0.5 mL/min at 40 °C.

<sup>c</sup> Polydispersity index ( $M_w/M_n$ ).

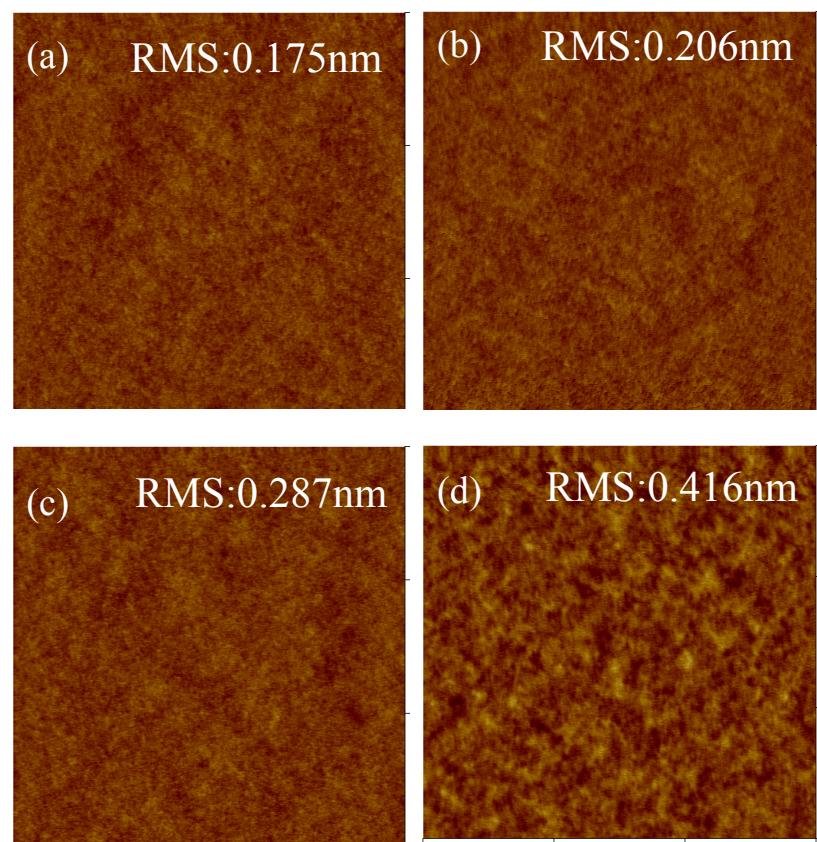
**Table S2.** Solubility<sup>a</sup> of the Polyimides

Polymer	Solvents						
	NMP	DMAc	DMF	DMSO	<i>m</i> -cresol	THF	CHCl <sub>3</sub>
<b>PI(F-ODPA)</b>	++	++	++	++	++	++	—
<b>PI(3S-ODPA)</b>	++	++	++	++	++	++	—

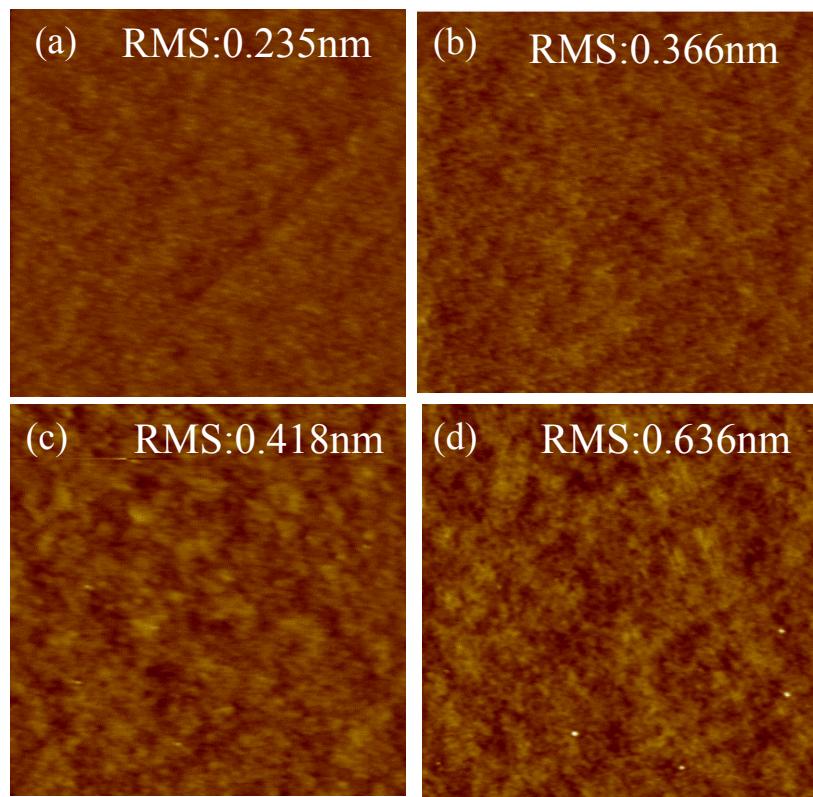
<sup>a</sup> The qualitative solubility was tested with 10 mg of a sample in 1 mL of stirred solvent. (++) soluble at room temperature, (+) soluble on heating, (+−) partial soluble on heating, (−) insoluble even on heating.



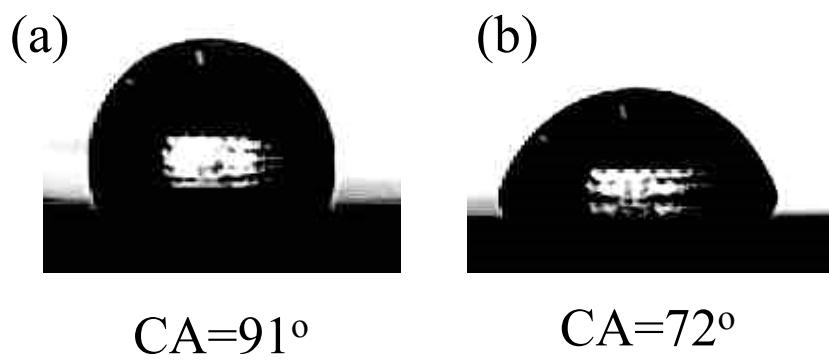
**Figure S1.** <sup>1</sup>H NMR spectrum of the polyimide **PI(3S-ODPA)**.



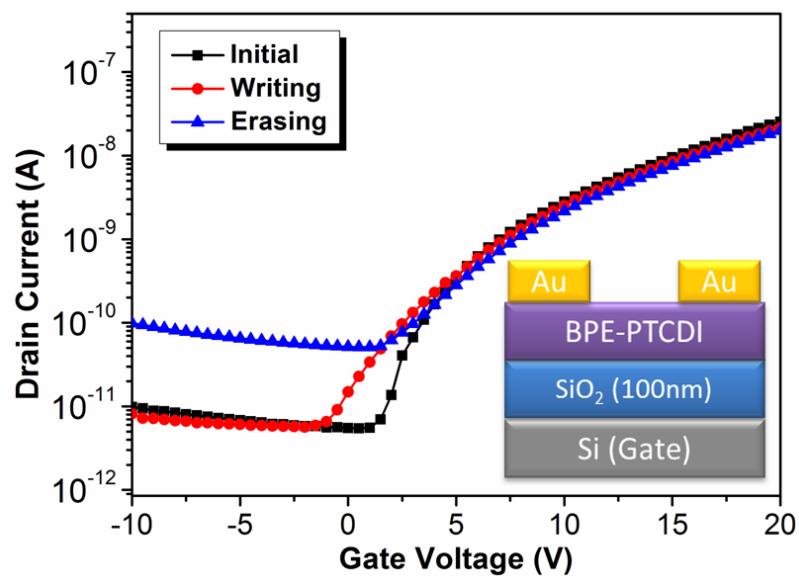
**Figure S2.** Atomic force microscopy (AFM) topographies of **PI(F-ODPA)** spin-coated on Si substrates (1 μm x 1 μm areas) with (a) 0wt%, (b) 5wt%, (c) 10wt%, and (d) 20wt% TiO<sub>2</sub> contents.



**Figure S3.** Atomic force microscopy (AFM) topographies of **PI(3S-ODPA)** spin-coated on Si substrates ( $1 \mu\text{m} \times 1 \mu\text{m}$  areas) with (a) 0wt%, (b) 5wt%, (c) 10wt%, and (d) 20wt%  $\text{TiO}_2$  contents.



**Figure S4.** Contact angles of the PI electrets: (a) **PI(F-ODPA)** and (b) **PI(3S-ODPA)**.



**Figure S5.** Shifts in transfer curves of BPE-PTCDI OFET memory device with bare  $\text{SiO}_2$  (100nm) as electrets at  $\pm 10\text{V}$  applied gate bias.